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**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 1.0 A



- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- 125 °C T<sub>J</sub> operation (V<sub>R</sub> < 5 V)
- Optimized for OR-ing applications
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The VS-10BQ015HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |                          |    |  |  |  |  |
|-----------------------------------|---|--------------------------|----|--|--|--|--|
| SYMBOL                            | CHARACTERISTICS                               | CHARACTERISTICS VALUES U |    |  |  |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                          | 1.0                      | А  |  |  |  |  |
| V <sub>RRM</sub>                  |   | 15                       | V  |  |  |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine                    | 140                      | А  |  |  |  |  |
| V <sub>F</sub>                    | 1.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.21                     | V  |  |  |  |  |
| Т <sub>Ј</sub>                    | Range   | -55 to +125              | °C |  |  |  |  |

| VOLTAGE RATINGS                      |                  |               |       |  |  |  |  |
|--------------------------------------|------------------|---------------|-------|--|--|--|--|
| PARAMETER                            | SYMBOL           | VS-10BQ015HM3 | UNITS |  |  |  |  |
| Maximum DC reverse voltage           | V <sub>R</sub>   | 15            | V     |  |  |  |  |
| Maximum working peak reverse voltage | V <sub>RWM</sub> | 25            | V     |  |  |  |  |

| ABSOLUTE MAXIMUM RATINGS                               |                    |  |  |        |       |  |
|--|--------------------|--|--|--------|-------|--|
| PARAMETER  | SYMBOL             | TEST CONDITIONS  |  | VALUES | UNITS |  |
| Maximum average forward current<br>See fig. 5          | I <sub>F(AV)</sub> | 50 % duty cycle at $T_L$ = 134 °C, rectangular waveform  |  | 1.0    | А     |  |
| Maximum peak one cycle<br>non-repetitive surge current |                    | 5 µs sine or 3 µs rect. pulse  | Following any rated load<br>condition and with rated | 140    | A     |  |
| See fig. 7   | IFSM               | 10 ms sine or 6 ms rect. pulse V <sub>RRM</sub> applied  |  | 40     |       |  |
| Non-repetitive avalanche energy                        | E <sub>AS</sub>    | $T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 2 \text{ mH}$  |  | 1.0    | mJ    |  |
| Repetitive avalanche current                           | I <sub>AR</sub>    | $\begin{array}{c} \mbox{Current decaying linearly to zero in 1 } \mu s \\ \mbox{Frequency limited by } T_J \mbox{ maximum } V_A = 1.5 \ x \ V_R \ typical \end{array} \ 1.0$ |  | А      |       |  |

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1



SMB

1.0 A

15 V

0.21 V

35 mA at 100 °C

125 °C

Single die

1.0 mJ

-0



**PRODUCT SUMMARY** 

Package

I<sub>F(AV)</sub>

 $V_R$ 

V<sub>F</sub> at I<sub>F</sub>

I<sub>RM</sub>

T<sub>J</sub> max.

**Diode variation** 

E<sub>AS</sub>

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| ELECTRICAL SPECIFICATIONS       |                                |                                   |                                    |       |    |  |
|---------------------------------|--------------------------------|-----------------------------------|------------------------------------|-------|----|--|
| PARAMETER                       | SYMBOL                         | TEST                              | VALUES                             | UNITS |    |  |
|                                 |                                | 1 A                               | T.I = 25 °C                        | 0.33  | V  |  |
| Maximum forward voltage drop    | V <sub>FM</sub> <sup>(1)</sup> | 2 A                               |                                    | 0.39  |    |  |
| See fig. 1                      |                                | 1 A                               | T, = 125 °C                        | 0.21  |    |  |
|                                 |                                | 2 A                               |                                    | 0.29  |    |  |
| Maximum reverse leakage current | I <sub>RM</sub>                | T <sub>J</sub> = 25 °C            | $V_{\rm B}$ = Rated V <sub>B</sub> | 0.5   | mA |  |
| See fig. 2                      |                                | T <sub>J</sub> = 100 °C           | $v_{\rm R}$ = Raied $v_{\rm R}$    | 35    |    |  |
| Threshold voltage               | V <sub>F(TO)</sub>             |                                   | -                                  | V     |    |  |
| Forward slope resistance        | r <sub>t</sub>                 | $T_J = T_J maximum$               | -                                  | mΩ    |    |  |
| Typical junction capacitance    | CT                             | $V_{R} = 5 V_{DC}$ , (test signal | 390                                | pF    |    |  |
| Typical series inductance       | LS                             | Measured lead to lead             | 2.0                                | nH    |    |  |
| Maximum voltage rate of change  | dV/dt                          | Rated V <sub>R</sub>              | 10 000                             | V/µs  |    |  |

#### Note

<sup>(1)</sup> Pulse width = 300  $\mu$ s, duty cycle = 2 %

| THERMAL - MECHANICAL SPECIFICATIONS             |                                  |                                      |             |       |  |  |
|---|----------------------------------|--------------------------------------|-------------|-------|--|--|
| PARAMETER                                       | SYMBOL                           | TEST CONDITIONS                      | VALUES      | UNITS |  |  |
| Maximum junction temperature range              | T <sub>J</sub> <sup>(1)</sup>    |                                      | -55 to +125 | °C    |  |  |
| Maximum storage temperature range               | T <sub>Stg</sub>                 |                                      | -55 to +150 | C     |  |  |
| Maximum thermal resistance, junction to lead    | R <sub>thJL</sub> <sup>(2)</sup> | DC operation<br>See fig. 4           | 36          | °C/W  |  |  |
| Maximum thermal resistance, junction to ambient | R <sub>thJA</sub>                | DC operation                         | 80          | C/W   |  |  |
| Approximate weight                              |                                  |                                      | 0.10        | g     |  |  |
| Approximate weight                              |                                  |                                      | 0.003       | oz.   |  |  |
| Marking device                                  |                                  | Case style SMB (similar to DO-214AA) | 1           | С     |  |  |

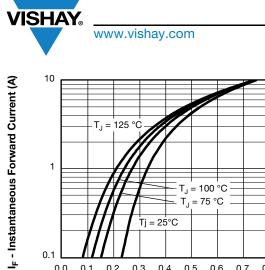
#### Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ (1)

(2) Mounted 1" square PCB

# **VS-10BQ015HM3**

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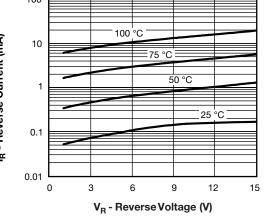


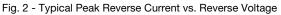
0.1

0.0 0.1 0.2 0.3 0.4

100 I<sub>R</sub> - Reverse Current (mA) 10 1 0.1 0.01 3 0 0.5 0.6 0.7 0.8 V<sub>FM</sub> - Forward Voltage Drop (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics





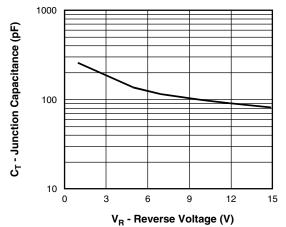


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

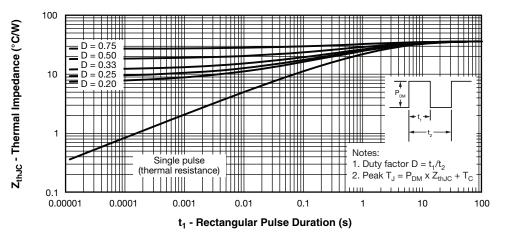
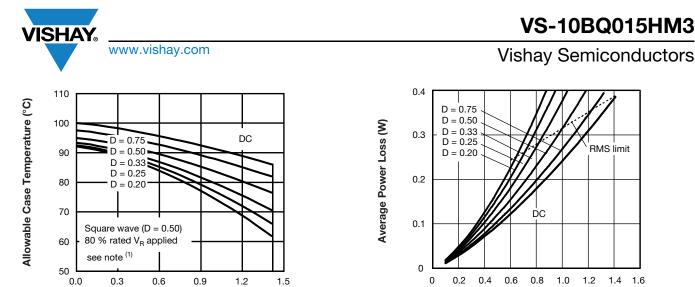


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

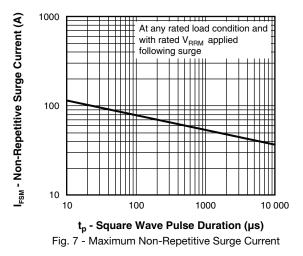
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1.6



#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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### **ORDERING INFORMATION TABLE**

| Device code | VS-      | 10     | в         | Q          | 015       | н       | М3       |
|-------------|----------|--------|-----------|------------|-----------|---------|----------|
|             | 1        | 2      | 3         | 4          | 5         | 6       | 7        |
|             | 1 .      | - Visl | nay Sen   | niconduc   | ctors pro | oduct   |          |
|             | 2        | - Cur  | rent rati | ng         |           |         |          |
|             | 3.       | - В=   | SMB       |            |           |         |          |
|             | 4        | - Q =  | Schott    | ky "Q" se  | eries     |         |          |
|             | 5        | - Vol  | tage rati | ng (015    | = 15 V)   |         |          |
|             | <b>6</b> | - H=   | AEC-Q     | 101 qua    | lified    |         |          |
|             | 7        | - Env  | vironmer  | ntal digit | :         |         |          |
|             |          | М3     | = halog   | en-free,   | RoHS o    | complia | nt and t |

| ORDERING INFORMATION (Example) |   |      |                                    |  |  |  |  |
|--------------------------------|---|------|------------------------------------|--|--|--|--|
| PREFERRED P/N                  | PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION |      |                                    |  |  |  |  |
| VS-10BQ015HM3/5BT              | 5BT   | 3200 | 13" diameter plastic tape and reel |  |  |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?95401 |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95403 |  |  |  |  |
| Packaging information      | www.vishay.com/doc?95404 |  |  |  |  |
| SPICE model                | www.vishay.com/doc?95666 |  |  |  |  |

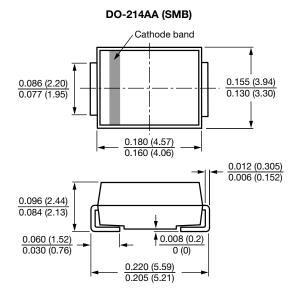


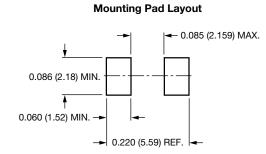
## **Outline Dimensions**

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**SMB** 

### **DIMENSIONS** in inches (millimeters)







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